

DATA SHEET

BFQ225 NPN video transistor

Product specification
Supersedes data of 1996 July 18
File under Discrete Semiconductors, SC05

1996 Sep 04

NPN video transistor

BFQ225

APPLICATIONS

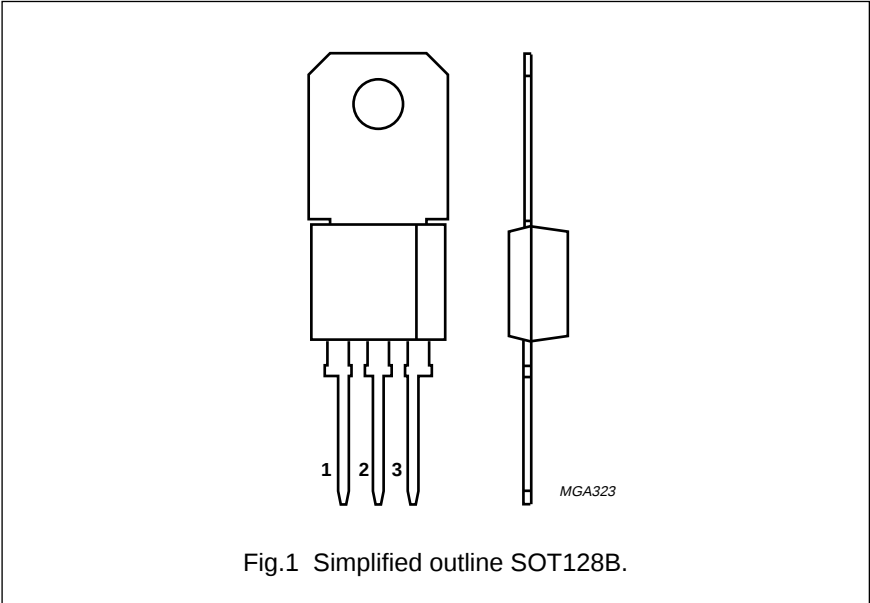
- Primarily intended for cascode output and buffer stages in high resolution colour monitors.

DESCRIPTION

NPN silicon transistor encapsulated in a 3-lead plastic SOT128B package.

PINNING

PIN	DESCRIPTION
1	emitter
2	collector
3	base



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	–	100	V
I _C	collector current (DC)		–	100	mA
P _{tot}	total power dissipation	T _{mb} = 25 °C	–	3.75	W
f _T	transition frequency	I _C = 25 mA; V _{CE} = 10 V	1	–	GHz
C _{re}	feedback capacitance	I _C = 0; V _{CB} = 10 V	1.7	–	pF
T _j	junction temperature		–	175	°C

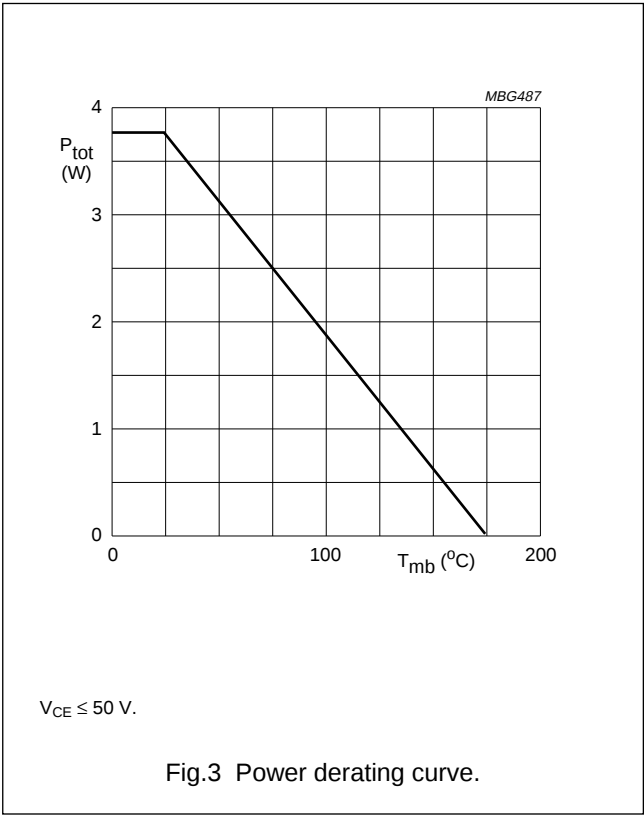
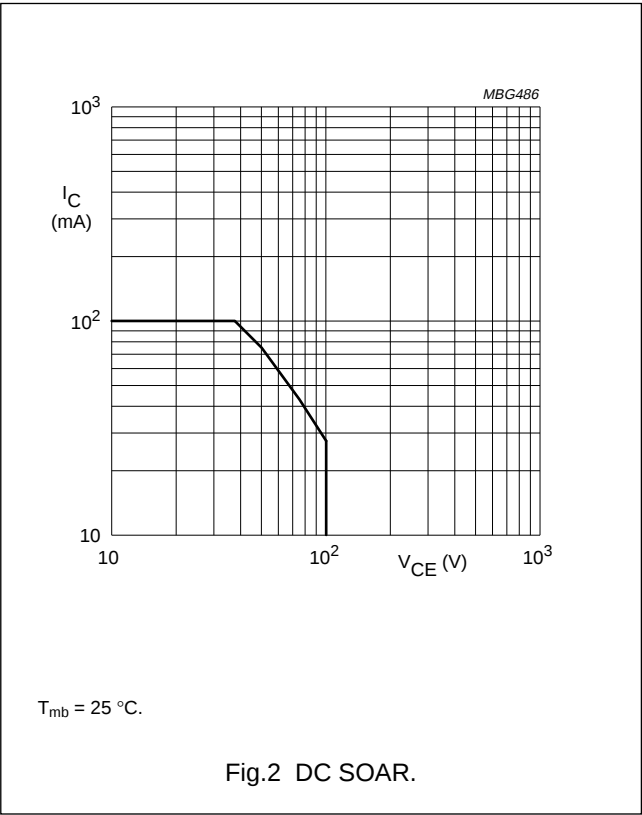
LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	–	100	V
V _{CER}	collector-emitter voltage	R _{BE} = 100 Ω	–	95	V
V _{EBO}	emitter-base voltage	open collector	–	3	V
I _C	collector current (DC)	see Fig.2	–	100	mA
I _{C(AV)}	average collector current	see Fig.2	–	100	mA
P _{tot}	total power dissipation	T _{mb} = 25 °C; see Fig.3	–	3.75	W
T _{stg}	storage temperature		–65	+175	°C
T _j	junction temperature		–	175	°C

NPN video transistor

BFQ225



THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-mb}$	thermal resistance from junction to mounting base	$P_{tot} = 3.75\text{ W}; T_{mb} = 25\text{ °C}$	40	K/W

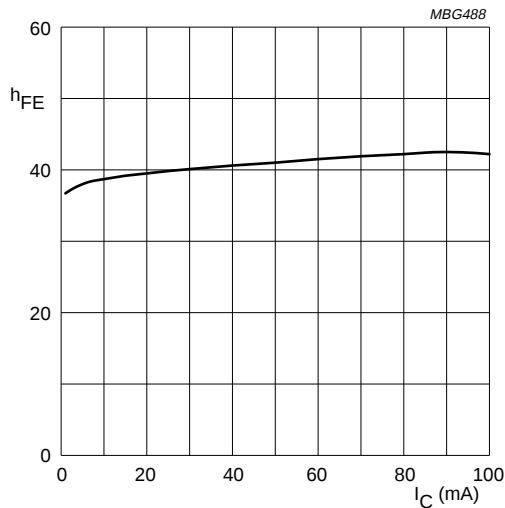
CHARACTERISTICS

$T_j = 25\text{ °C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = 0.1\text{ mA}; I_E = 0$	100	—	—	V
$V_{(BR)CER}$	collector-emitter breakdown voltage	$I_C = 1\text{ mA}; R_{BE} = 100\ \Omega$	95	—	—	V
$V_{(BR)EBO}$	emitter-base breakdown voltage	$I_C = 0; I_E = 0.1\text{ mA}$	3	—	—	V
I_{CES}	collector-emitter leakage current	$V_{CE} = 50\text{ V}; V_{BE} = 0$	—	—	100	μA
h_{FE}	DC current gain	$I_C = 25\text{ mA}; V_{CE} = 10\text{ V};$ see Fig.4	20	—	—	
f_T	transition frequency	$I_C = 25\text{ mA}; V_{CE} = 10\text{ V};$ $f = 500\text{ MHz};$ see Fig.5	—	1	—	GHz
C_{re}	feedback capacitance	$I_C = 0; V_{CB} = 10\text{ V}; f = 1\text{ MHz};$ see Fig.6	—	1.7	—	pF

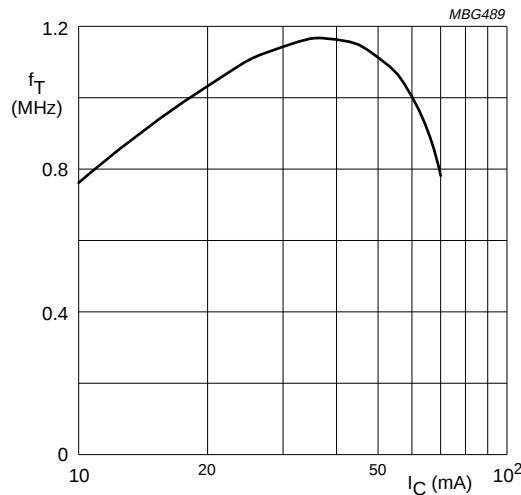
NPN video transistor

BFQ225



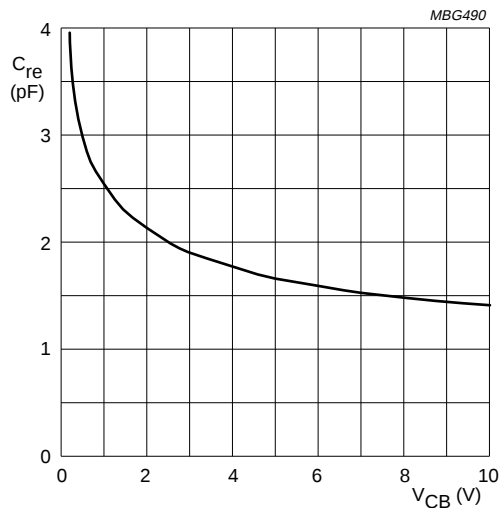
$V_{CE} = 10\text{ V}$; $t_p = 500\text{ }\mu\text{s}$.

Fig.4 DC current gain as a function of collector current; typical values.



$V_{CE} = 10\text{ V}$; $f = 500\text{ MHz}$.

Fig.5 Transition frequency as a function of collector current; typical values.



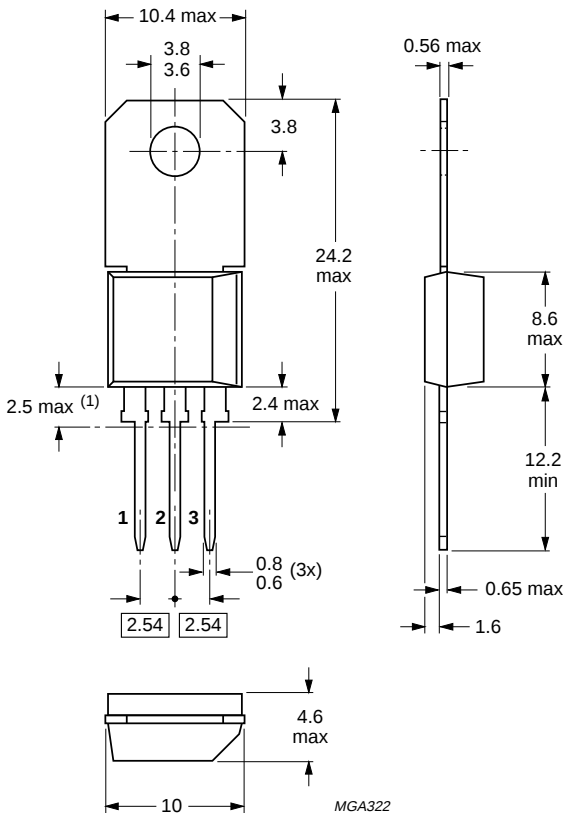
$f = 1\text{ MHz}$.

Fig.6 Feedback capacitance as a function of collector-base voltage; typical values.

NPN video transistor

BFQ225

PACKAGE OUTLINE



Dimensions in mm.

Fig.7 SOT128B.

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BFQ225

DEFINITIONS

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.